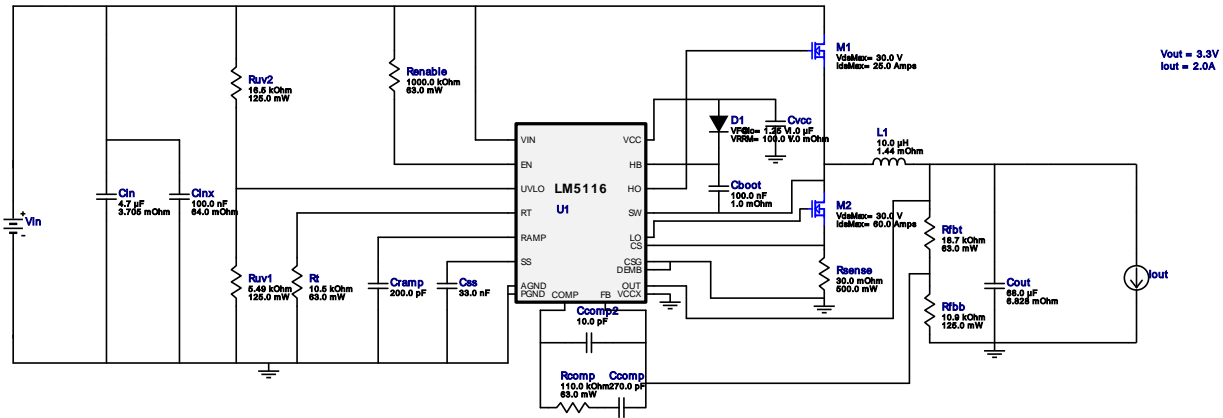


## WEBENCH® Design Report

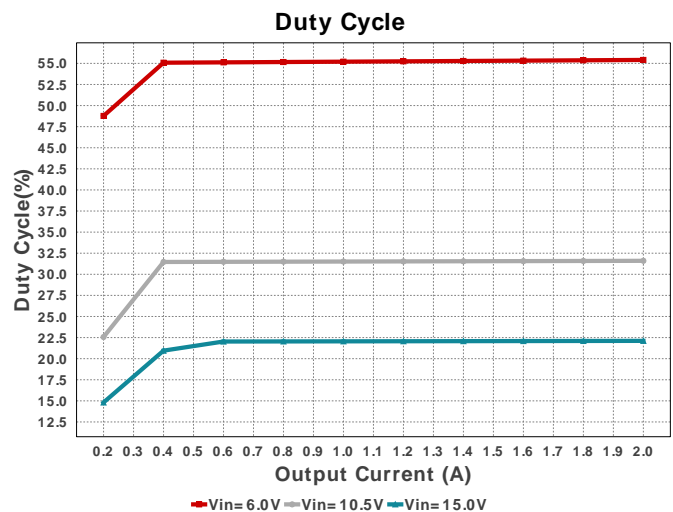
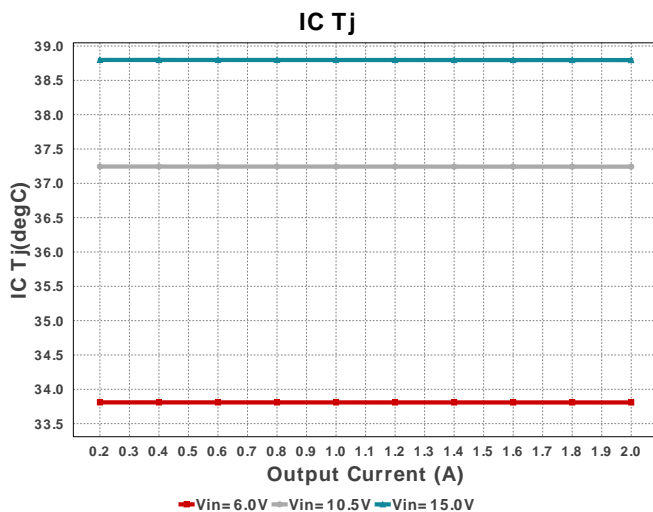
Design : 17 LM5116MH/NOPB  
LM5116MH/NOPB 6V-15V to 3.30V @ 2A



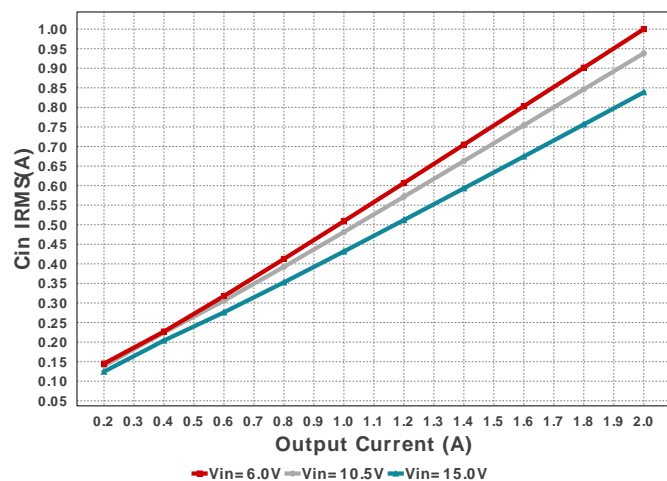
## Electrical BOM

Name	Manufacturer	Part Number	Properties	Qty	Price	Footprint
Cboot	MuRata	GRM155R71C104KA88D Series= X7R	Cap= 100.0 nF ESR= 1.0 mOhm VDC= 16.0 V IRMS= 0.0 A	1	\$0.01	0402 3 mm <sup>2</sup>
Ccomp	Taiyo Yuden	UMK105CG271JV-F Series= C0G/NP0	Cap= 270.0 pF VDC= 50.0 V IRMS= 0.0 A	1	\$0.01	0402 3 mm <sup>2</sup>
Ccomp2	Kemet	C0805C100M4GACTU Series= C0G/NP0	Cap= 10.0 pF VDC= 16.0 V IRMS= 0.0 A	1	\$0.01	0805 7 mm <sup>2</sup>
Cin	MuRata	GRM31CR71E475KA88L Series= X7R	Cap= 4.7 uF ESR= 3.705 mOhm VDC= 25.0 V IRMS= 2.8649 A	1	\$0.08	1206_190 11 mm <sup>2</sup>
Cinx	Kemet	C0805C104M5RACTU Series= X7R	Cap= 100.0 nF ESR= 64.0 mOhm VDC= 50.0 V IRMS= 1.64 A	1	\$0.01	0805 7 mm <sup>2</sup>
Cout	TDK	C5750X5R1A686M230KA Series= X5R	Cap= 68.0 uF ESR= 6.828 mOhm VDC= 10.0 V IRMS= 3.4939 A	1	\$1.07	2220_250 54 mm <sup>2</sup>
Cramp	Samsung Electro-Mechanics	CL05C201JB5NNNC Series= C0G/NP0	Cap= 200.0 pF VDC= 50.0 V IRMS= 0.0 A	1	\$0.01	0402 3 mm <sup>2</sup>
Css	TDK	CGA4J2C0G1H333J125AA Series= C0G/NP0	Cap= 33.0 nF VDC= 50.0 V IRMS= 0.0 A	1	\$0.09	0805 7 mm <sup>2</sup>
Cvcc	Taiyo Yuden	TMK212B7105KG-T Series= X7R	Cap= 1.0 uF ESR= 1.0 mOhm VDC= 25.0 V IRMS= 0.0 A	1	\$0.02	0805 7 mm <sup>2</sup>
D1	Nexperia	BAS516,115	VF@Io= 1.25 V VRRM= 100.0 V	1	\$0.21	SOD-523 5 mm <sup>2</sup>
L1	Würth Elektronik	74436411000	L= 10.0 uH 1.44 mOhm	1	\$4.87	WE-HCF_2815 627 mm <sup>2</sup>

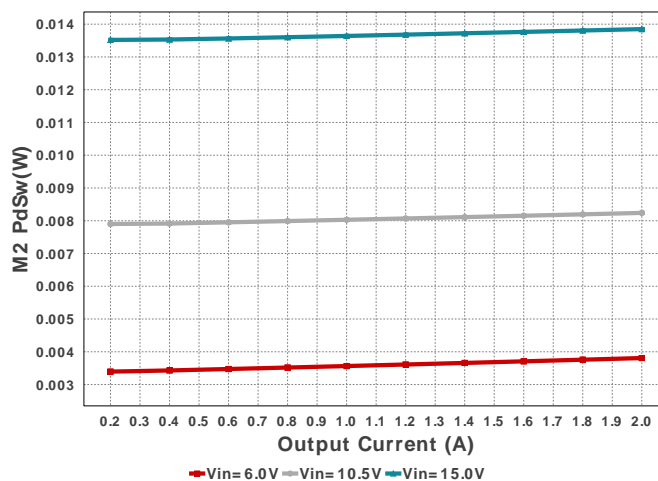
Name	Manufacturer	Part Number	Properties	Qty	Price	Footprint
M1	Texas Instruments	CSD17579Q5A	VdsMax= 30.0 V IdsMax= 25.0 Amps	1	\$0.16	 TRANS_NexFET_Q5A 55 mm <sup>2</sup>
M2	Texas Instruments	CSD17577Q5A	VdsMax= 30.0 V IdsMax= 60.0 Amps	1	\$0.20	 TRANS_NexFET_Q5A 55 mm <sup>2</sup>
Rcomp	Vishay-Dale	CRCW0402110KFKED Series= CRCW..e3	Res= 110.0 kOhm Power= 63.0 mW Tolerance= 1.0%	1	\$0.01	 0402 3 mm <sup>2</sup>
Renable	Vishay-Dale	CRCW04021M00FKED Series= CRCW..e3	Res= 1000.0 kOhm Power= 63.0 mW Tolerance= 1.0%	1	\$0.01	 0402 3 mm <sup>2</sup>
Rfbb	Yageo	RT0805BRD0710K9L Series= ?	Res= 10.9 kOhm Power= 125.0 mW Tolerance= 0.1%	1	\$0.06	 0805 7 mm <sup>2</sup>
Rfbt	Vishay-Dale	CRCW040218K7FKED Series= CRCW..e3	Res= 18.7 kOhm Power= 63.0 mW Tolerance= 1.0%	1	\$0.01	 0402 3 mm <sup>2</sup>
Rsense	Stackpole Electronics Inc	CSR1206FK30L0 Series= ?	Res= 30.0 mOhm Power= 500.0 mW Tolerance= 1.0%	1	\$0.10	 1206 11 mm <sup>2</sup>
Rt	Vishay-Dale	CRCW040210K5FKED Series= CRCW..e3	Res= 10.5 kOhm Power= 63.0 mW Tolerance= 1.0%	1	\$0.01	 0402 3 mm <sup>2</sup>
Ruv1	Panasonic	ERJ-6ENF5491V Series= ERJ-6E	Res= 5.49 kOhm Power= 125.0 mW Tolerance= 1.0%	1	\$0.01	 0805 7 mm <sup>2</sup>
Ruv2	Vishay-Dale	CRCW080516K5FKEA Series= CRCW..e3	Res= 16.5 kOhm Power= 125.0 mW Tolerance= 1.0%	1	\$0.01	 0805 7 mm <sup>2</sup>
U1	Texas Instruments	LM5116MH/NOPB	Switcher	1	\$2.56	 MXA20A 71 mm <sup>2</sup>



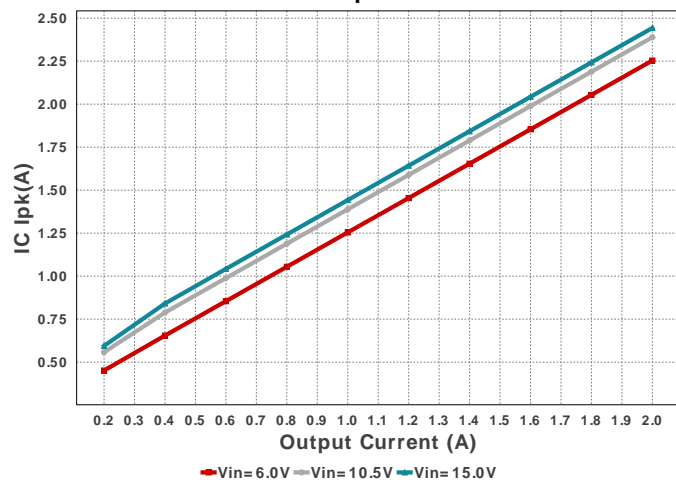
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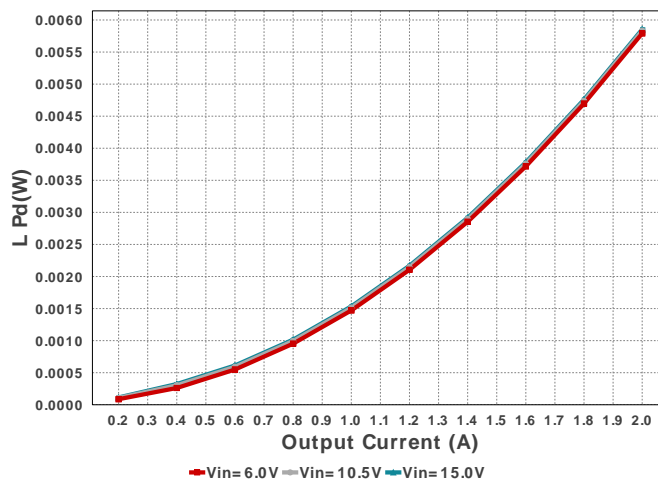
M2 PdSw



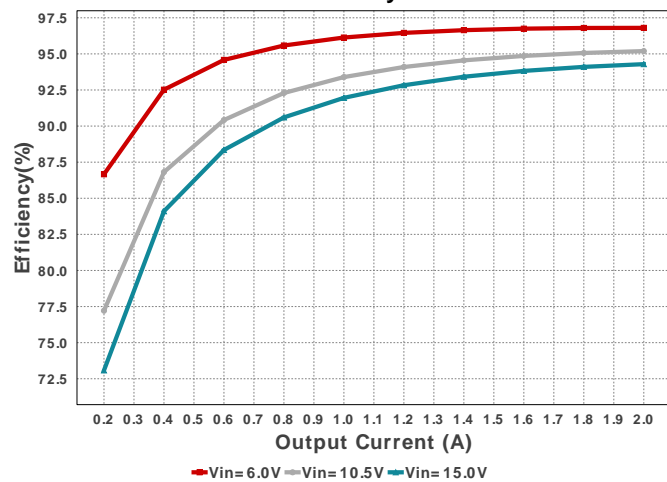
IC Ipk



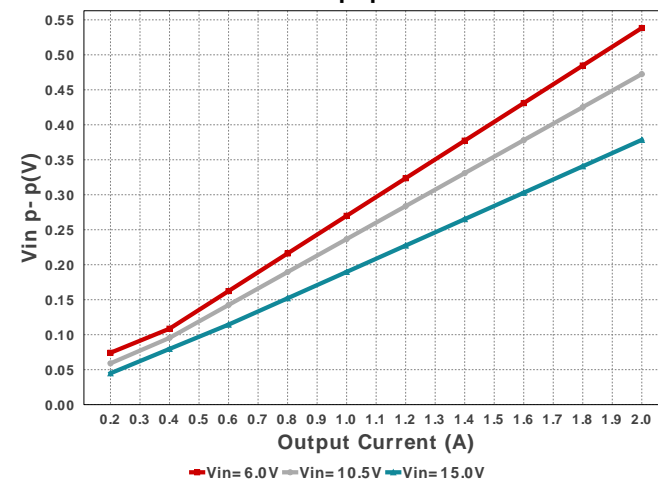
L Pd

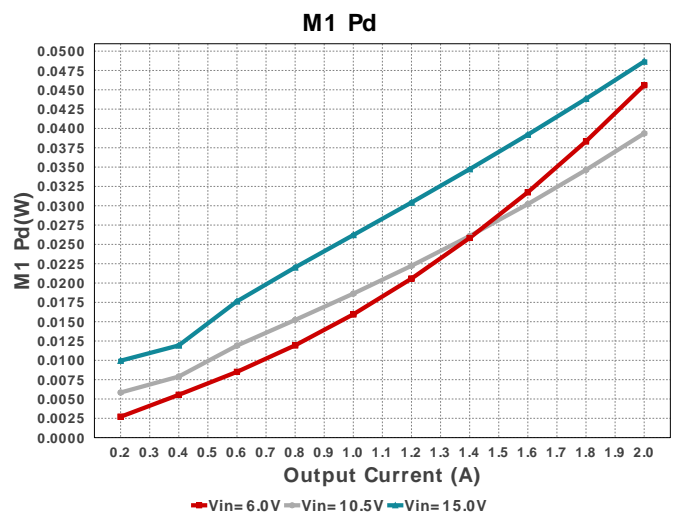
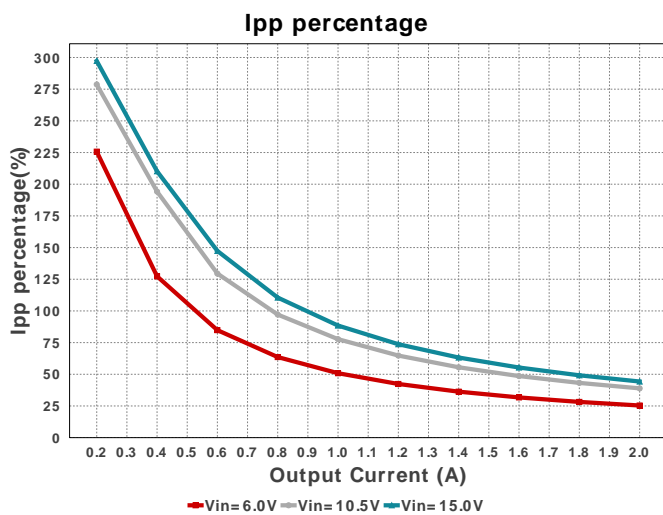
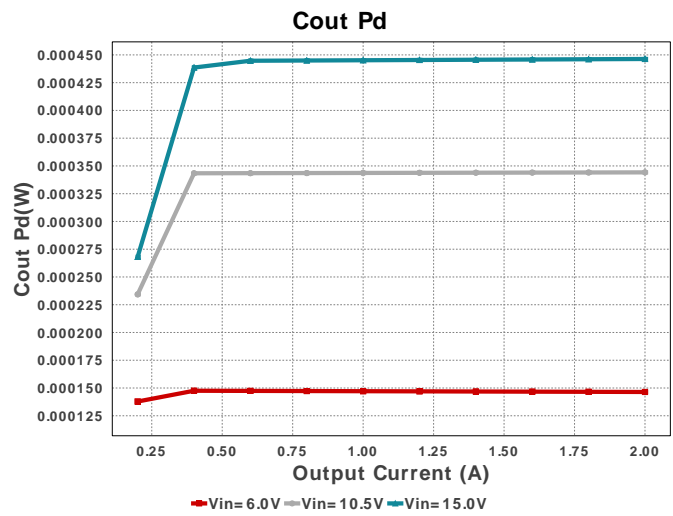
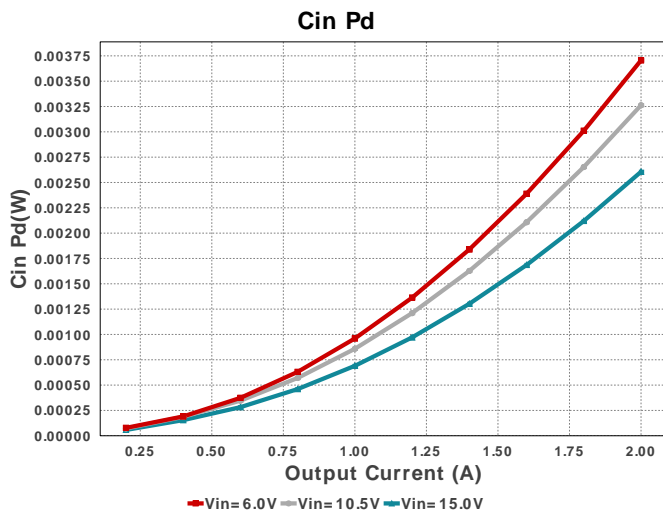
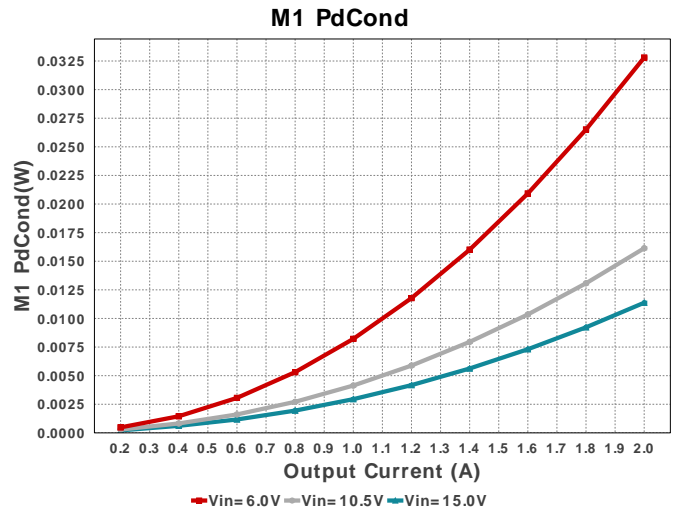
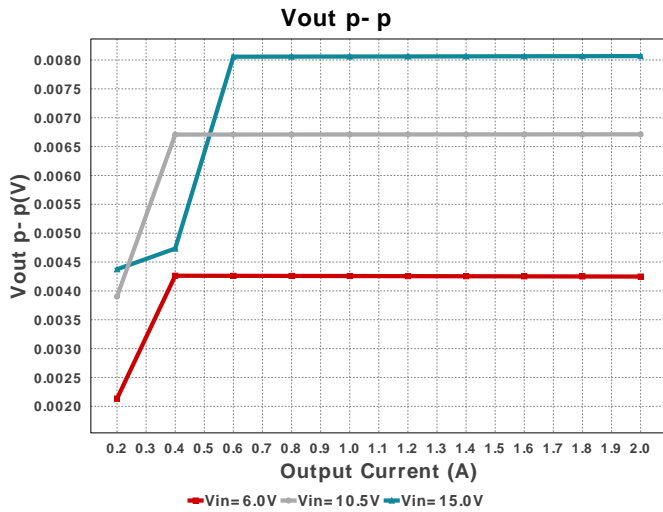


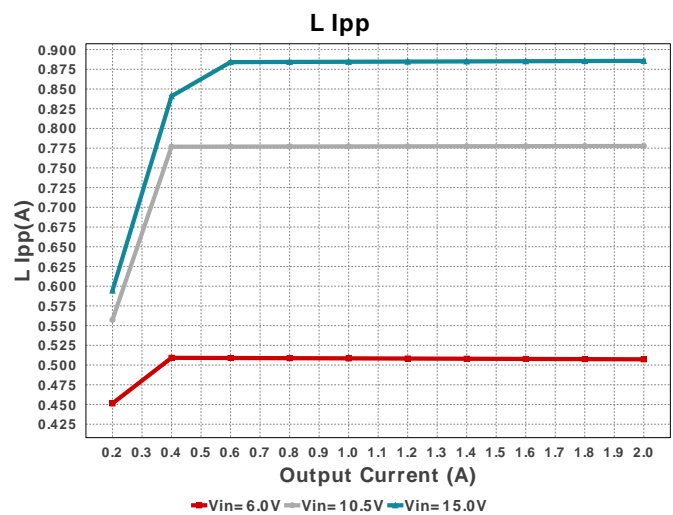
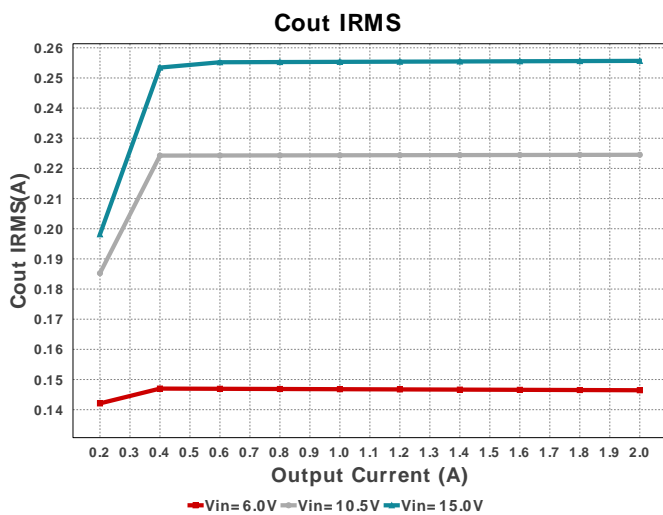
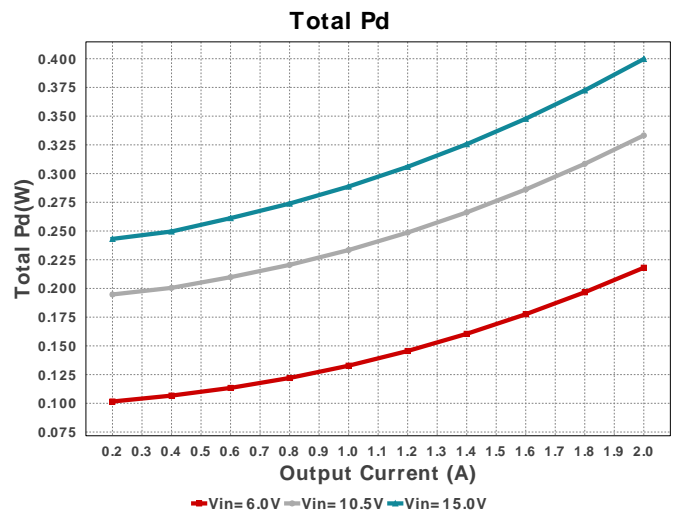
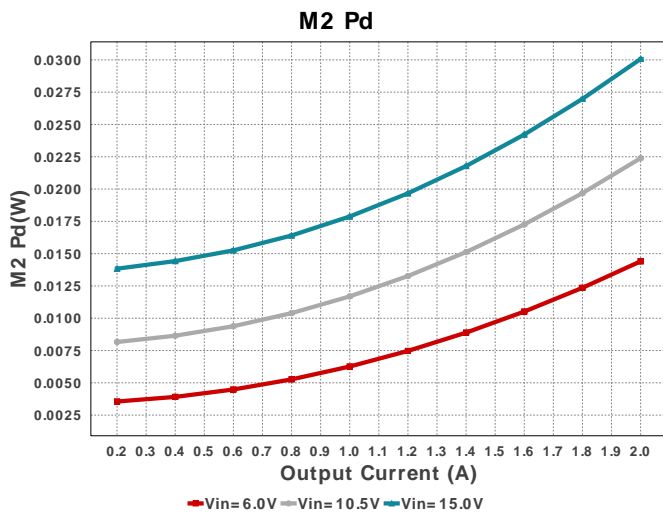
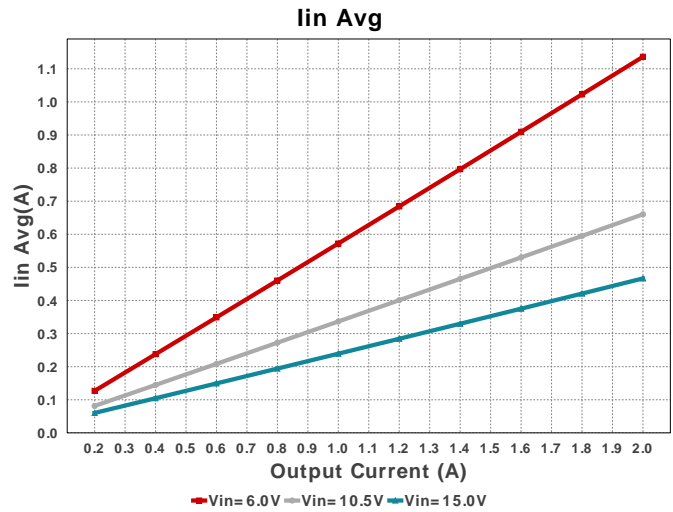
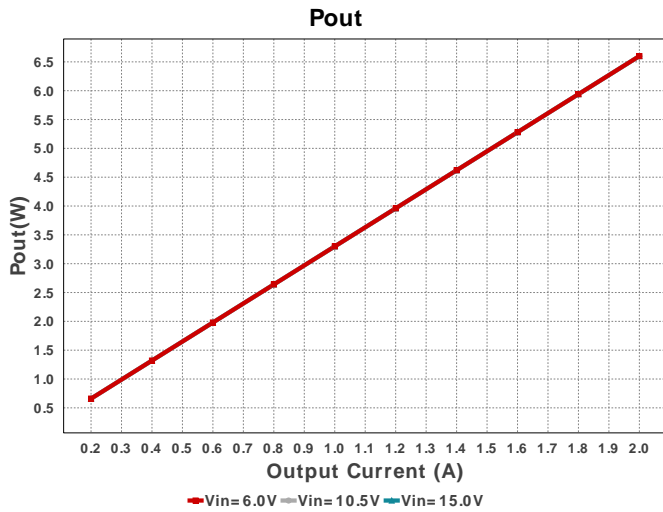
Efficiency

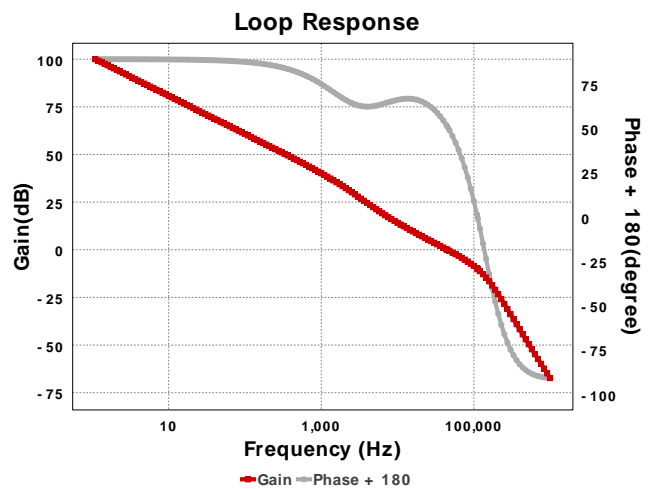
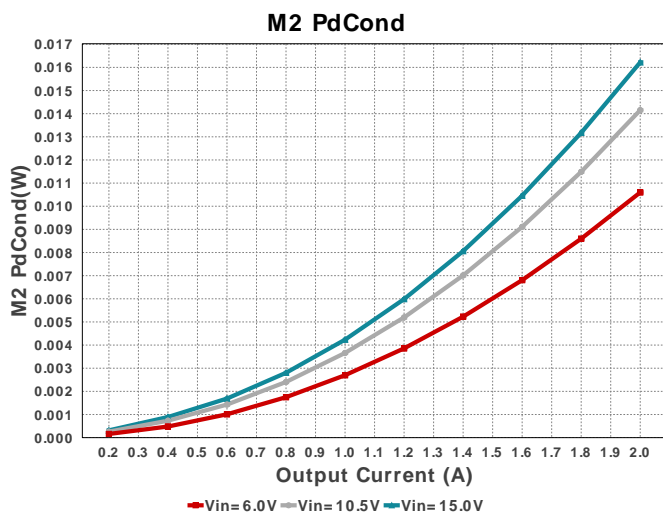
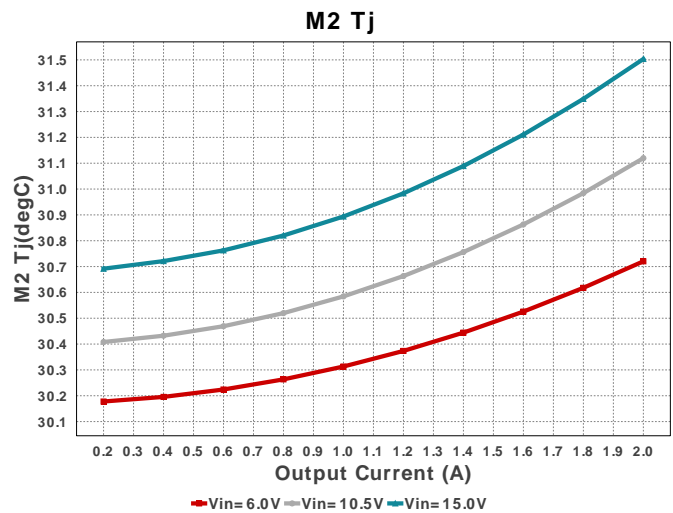
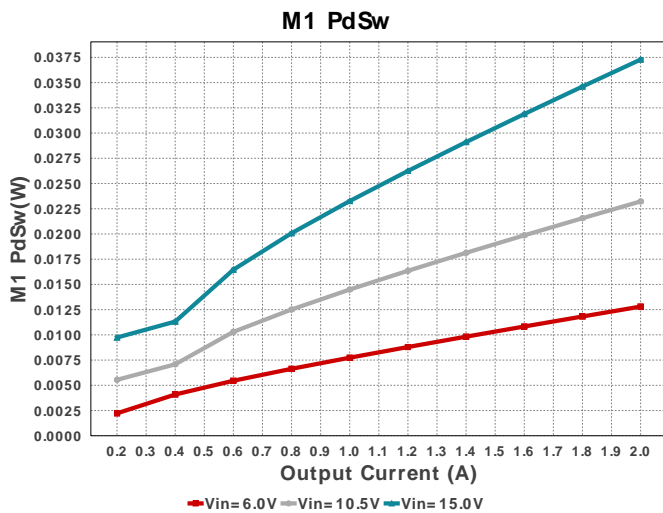
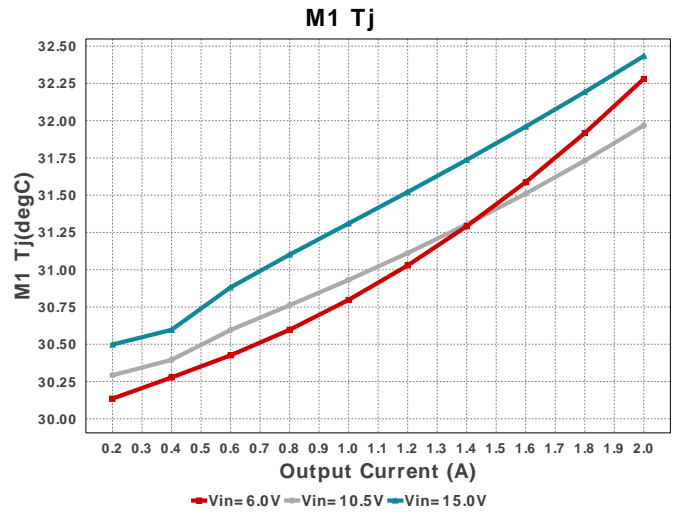
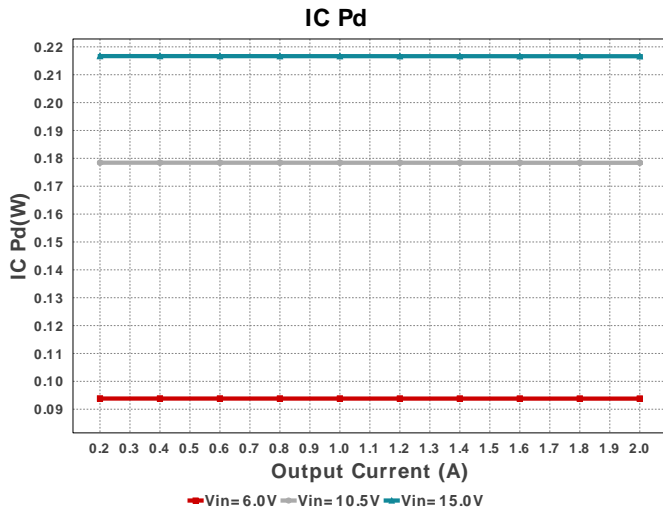


Vin p-p









## Operating Values

#	Name	Value	Category	Description
1.	Cin IRMS	838.58 mA	Capacitor	Input capacitor RMS ripple current
2.	Cin Pd	2.605 mW	Capacitor	Input capacitor power dissipation
3.	Cout IRMS	255.638 mA	Capacitor	Output capacitor RMS ripple current
4.	Cout Pd	65.351 $\mu$ W	Capacitor	Output capacitor power dissipation
5.	IC IpK	2.443 A	IC	Peak switch current in IC
6.	IC Pd	216.63 mW	IC	IC power dissipation
7.	IC Tj	38.665 degC	IC	IC junction temperature
8.	IC Tolerance	16.0 mV	IC	IC Feedback Tolerance
9.	ICThetaJA	40.0 degC/W	IC	IC junction-to-ambient thermal resistance
10.	Iin Avg	466.52 mA	IC	Average input current



#	Name	Value	Category	Description
11.	Ipp percentage	44.278 %	Inductor	Inductor ripple current percentage (with respect to average inductor current)
12.	L Ipp	885.56 mA	Inductor	Peak-to-peak inductor ripple current
13.	L Pd	5.854 mW	Inductor	Inductor power dissipation
14.	M1 Pd	48.659 mW	Mosfet	M1 MOSFET total power dissipation
15.	M1 PdCond	11.373 mW	Mosfet	M1 MOSFET conduction losses
16.	M1 PdSw	37.286 mW	Mosfet	M1 MOSFET switching losses
17.	M1 Tj	32.433 degC	Mosfet	M1 MOSFET junction temperature
18.	M2 Pd	30.07 mW	Mosfet	M2 MOSFET total power dissipation
19.	M2 PdCond	16.22 mW	Mosfet	M2 MOSFET conduction losses
20.	M2 PdSw	13.85 mW	Mosfet	M2 MOSFET switching losses
21.	M2 Tj	31.504 degC	Mosfet	M2 MOSFET junction temperature
22.	Cin Pd	2.605 mW	Power	Input capacitor power dissipation
23.	Cout Pd	65.351 $\mu$ W	Power	Output capacitor power dissipation
24.	IC Pd	216.63 mW	Power	IC power dissipation
25.	L Pd	5.854 mW	Power	Inductor power dissipation
26.	M1 Pd	48.659 mW	Power	M1 MOSFET total power dissipation
27.	M1 PdCond	11.373 mW	Power	M1 MOSFET conduction losses
28.	M1 PdSw	37.286 mW	Power	M1 MOSFET switching losses
29.	M2 Pd	30.07 mW	Power	M2 MOSFET total power dissipation
30.	M2 PdCond	16.22 mW	Power	M2 MOSFET conduction losses
31.	M2 PdSw	13.85 mW	Power	M2 MOSFET switching losses
32.	Total Pd	398.875 mW	Power	Total Power Dissipation
33.	BOM Count	22	System	Total Design BOM count
34.	Cross Freq	45.023 kHz	Information System	Bode plot crossover frequency
35.	Duty Cycle	22.106 %	Information System	Duty cycle
36.	Efficiency	94.3 %	Information System	Steady state efficiency
37.	FootPrint	958.0 mm <sup>2</sup>	Information System	Total Foot Print Area of BOM components
38.	Frequency	291.375 kHz	Information System	Switching frequency
39.	Gain Marg	-8.237 dB	Information System	Bode Plot Gain Margin
40.	Iout	2.0 A	Information System	Iout operating point
41.	Low Freq Gain	99.995 dB	Information System	Gain at 1Hz
42.	Mode	CCM	Information System	Conduction Mode
43.	Phase Marg	45.712 deg	Information System	Bode Plot Phase Margin
44.	Pout	6.599 W	Information System	Total output power
45.	Total BOM	\$9.53	Information System	Total BOM Cost
46.	Vin	15.0 V	Information System	Vin operating point
47.	Vin p-p	380.658 mV	Information System	Peak-to-peak input voltage
48.	Vout	3.299 V	Information System	Operational Output Voltage
49.	Vout Actual	3.299 V	Information System	Vout Actual calculated based on selected voltage divider resistors
50.	Vout Tolerance	2.022 %	Information System	Vout Tolerance based on IC Tolerance (no load) and voltage divider resistors if applicable
51.	Vout p-p	5.878 mV	Information System	Peak-to-peak output ripple voltage

## Design Inputs

Name	Value	Description
Iout	2.0	Maximum Output Current
VinMax	15.0	Maximum input voltage
VinMin	6.0	Minimum input voltage
Vout	3.3	Output Voltage
base_pn	LM5116	Base Product Number
source	DC	Input Source Type
Ta	30.0	Ambient temperature

## WEBENCH® Assembly

### Component Testing

Some published data on components in datasheets such as Capacitor ESR and Inductor DC resistance is based on conservative values that will guarantee that the components always exceed the specification. For design purposes it is usually better to work with typical values. Since this data is not always available it is a good practice to measure the Capacitance and ESR values of  $C_{in}$  and  $C_{out}$ , and the inductance and DC resistance of  $L1$  before assembly of the board. Any large discrepancies in values should be electrically simulated in WEBENCH to check for instabilities and thermally simulated in WebTHERM to make sure critical temperatures are not exceeded.

### Soldering Component to Board

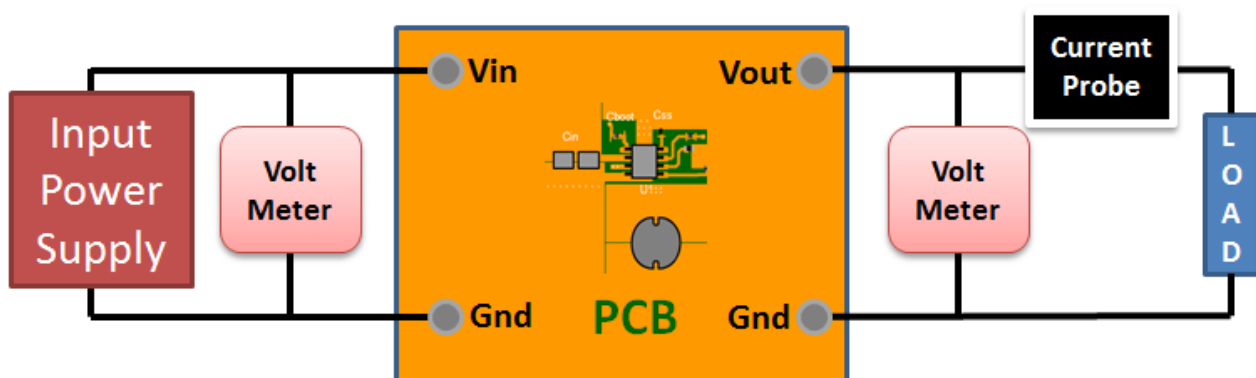
If board assembly is done in house it is best to tack down one terminal of a component on the board then solder the other terminal. For surface mount parts with large tabs, such as the DPAK, the tab on the back of the package should be pre-tinned with solder, then tacked into place by one of the pins. To solder the tab down to the board place the iron down on the board while resting against the tab, heating both surfaces simultaneously. Apply light pressure to the top of the plastic case until the solder flows around the part and the part is flush with the PCB. If the solder is not flowing around the board you may need a higher wattage iron (generally 25W to 30W is enough).

### Initial Startup of Circuit

It is best to initially power up the board by setting the input supply voltage to the lowest operating input voltage 6.0V and set the input supply's current limit to zero. With the input supply off connect up the input supply to  $V_{in}$  and GND. Connect a digital volt meter and a load if needed to set the minimum load of the design from  $V_{out}$  and GND. Turn on the input supply and slowly turn up the current limit on the input supply. If the voltage starts to rise on the input supply continue increasing the input supply current limit while watching the output voltage. If the current increases on the input supply, but the voltage remains near zero, then there may be a short or a component misplaced on the board. Power down the board and visually inspect for solder bridges and recheck the diode and capacitor polarities. Once the power supply circuit is operational then more extensive testing may include full load testing, transient load and line tests to compare with simulation results.

### Load Testing

The setup is the same as the initial startup, except that an additional digital voltmeter is connected between  $V_{in}$  and GND, a load is connected between  $V_{out}$  and GND and a current meter is connected in series between  $V_{out}$  and the load. The load must be able to handle at least rated output power + 50% ( 7.5 watts for this design). Ideally the load is supplied in the form of a variable load test unit. It can also be done in the form of suitably large power resistors. When using an oscilloscope to measure waveforms on the prototype board, the ground leads of the oscilloscope probes should be as short as possible and the area of the loop formed by the ground lead should be kept to a minimum. This will help reduce ground lead inductance and eliminate EMI noise that is not actually present in the circuit.



### Design Assistance

1. Master key : 17E312EF2778B210[v1]
2. **LM5116** Product Folder : <http://www.ti.com/product/LM5116> : contains the data sheet and other resources.



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